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Applications of Embedded - Microcontroller,

Details	
Product Status	Obsolete
Module/Board Type	MCU, FPGA
Core Processor	ARM® Cortex®-A9
Co-Processor	Zynq-7000 (Z-7030)
Speed	-
Flash Size	32MB
RAM Size	1GB
Connector Type	Samtec UFPS
Size / Dimension	2.05" x 2.99" (52mm x 76mm)
Operating Temperature	-40°C ~ 85°C
Purchase URL	https://www.e-xfl.com/product-detail/trenz-electronic/te0745-02-30-1i

Table 2: **Recommended Operating Conditions (1)(2) *(Cont'd)***

Symbol	Description	Min	Typ	Max	Units
PL					
V_{CCINT}	Internal supply voltage	0.97	1.00	1.03	V
V_{CCAUX}	Auxiliary supply voltage	1.71	1.80	1.89	V
V_{CCBRAM}	Block RAM supply voltage	0.97	1.00	1.03	V
V_{CCO}(6)(7)	Supply voltage for 3.3V HR I/O banks	1.14	–	3.465	V
	Supply voltage for 1.8V HP I/O banks	1.14	–	1.89	V
V_{CCAUX_IO}	Auxiliary supply voltage when set to 1.8V	1.71	1.80	1.89	V
	Auxiliary supply voltage when set to 2.0V	1.94	2.00	2.06	V
V_{IN}(5)	I/O input voltage	–0.20	–	V_{CCO} + 0.20	V
	I/O input voltage for V_{REF} and differential I/O standards	–0.20	–	2.625	
I_{IN}(8)	Maximum current through any (PS or PL) pin in a powered or unpowered bank when forward biasing the clamp diode	–	–	10	mA
V_{CCBATT}(9)	Battery voltage	1.0	–	1.89	V
GTX Transceiver					
$V_{MGTAVCC}$(10)	Analog supply voltage for the GTX transceiver QPLL frequency range ≤ 10.3125 GHz(11)(12)	0.97	1.0	1.08	V
	Analog supply voltage for the GTX transceiver QPLL frequency range > 10.3125 GHz	1.02	1.05	1.08	
$V_{MGTAVTT}$(10)	Analog supply voltage for the GTX transmitter and receiver termination circuits	1.17	1.2	1.23	V
$V_{MGTVCCAUX}$(10)	Auxiliary analog QPLL voltage supply for the transceivers	1.75	1.80	1.85	V
$V_{MGTAVTTRCAL}$(10)	Analog supply voltage for the resistor calibration circuit of the GTX transceiver column	1.17	1.2	1.23	V
XADC					
V_{CCADC}	XADC supply relative to GNDADC	1.71	1.80	1.89	V
V_{REFP}	Externally supplied reference voltage	1.20	1.25	1.30	V
Temperature					
T_j	Junction temperature operating range for commercial (C) temperature devices	0	–	85	°C
	Junction temperature operating range for extended (E) temperature devices	0	–	100	°C
	Junction temperature operating range for industrial (I) temperature devices	–40	–	100	°C

Notes:

1. All voltages are relative to ground. The PL and PS share a common ground.
2. For the design of the power distribution system consult UG933, *Zynq-7000 All Programmable SoC PCB Design and Pin Planning Guide*.
3. When the processor cores operate $F_{CPU\_6X4X\_621\_MAX}$ at 1 GHz (-3E speed grade), the V_{CCPINT} minimum is 0.97V and the V_{CCPINT} maximum is 1.03V.
4. Applies to both MIO supply banks V_{CCO_MIO0} and V_{CCO_MIO1}.
5. The lower absolute voltage specification always applies.
6. Configuration data is retained even if V_{CCO} drops to 0V.
7. Includes V_{CCO} of 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.
8. A total of 200 mA per PS or PL bank should not be exceeded.
9. V_{CCBATT} is required only when using bitstream encryption. If battery is not used, connect V_{CCBATT} to either ground or V_{CCAUX}.
10. Each voltage listed requires the filter circuit described in UG476: *7 Series FPGAs GTX/GTH Transceivers User Guide*.
11. For data rates ≤ 10.3125 Gb/s, $V_{MGTAVCC}$ should be 1.0V ±3% for lower power consumption.
12. For lower power consumption, $V_{MGTAVCC}$ should be 1.0V ±3% over the entire CPLL frequency range.

Table 3: **DC Characteristics Over Recommended Operating Conditions**

Symbol	Description	Min	Typ[1]	Max	Units
V_{DRINT}	Data retention V_{CCINT} voltage (below which configuration data might be lost)	0.75	–	–	V
V_{DRI}	Data retention V_{CCAUX} voltage (below which configuration data might be lost)	1.5	–	–	V
I_{REF}	V_{REF} leakage current per pin	–	–	15	µA
I_L	Input or output leakage current per pin (sample-tested)	–	–	15	µA
C_{IN}[2]	PL die input capacitance at the pad	–	–	8	pF
C_{PIN}[2]	PS die input capacitance at the pad	–	–	8	pF
I_{RPU}	Pad pull-up (when selected) @ V_{IN} = 0V, V_{CCO} = 3.3V	90	–	330	µA
	Pad pull-up (when selected) @ V_{IN} = 0V, V_{CCO} = 2.5V	68	–	250	µA
	Pad pull-up (when selected) @ V_{IN} = 0V, V_{CCO} = 1.8V	34	–	220	µA
	Pad pull-up (when selected) @ V_{IN} = 0V, V_{CCO} = 1.5V	23	–	150	µA
	Pad pull-up (when selected) @ V_{IN} = 0V, V_{CCO} = 1.2V	12	–	120	µA
I_{RPD}	Pad pull-down (when selected) @ V_{IN} = 3.3V	68	–	330	µA
	Pad pull-down (when selected) @ V_{IN} = 1.8V	45	–	180	µA
I_{CCADC}	Analog supply current, analog circuits in powered up state	–	–	25	mA
I_{BATT}[3]	Battery supply current	–	–	150	nA
R_{IN_TERM}[4]	Thevenin equivalent resistance of programmable input termination to V_{CCO}/2 (UNTUNED_SPLIT_40) for commercial (C), industrial (I), and extended (E) temperature devices	28	40	55	Ω
	Thevenin equivalent resistance of programmable input termination to V_{CCO}/2 (UNTUNED_SPLIT_50) for commercial (C), industrial (I), and extended (E) temperature devices	35	50	65	Ω
	Thevenin equivalent resistance of programmable input termination to V_{CCO}/2 (UNTUNED_SPLIT_60) for commercial (C), industrial (I), and extended (E) temperature devices	44	60	83	Ω
n	Temperature diode ideality factor	–	1.010	–	–
r	Temperature diode series resistance	–	2	–	Ω

Notes:

1. Typical values are specified at nominal voltage, 25°C.
2. This measurement represents the die capacitance at the pad, not including the package.
3. Maximum value specified for worst case process at 25°C.
4. Termination resistance to a V_{CCO}/2 level.

PS Switching Characteristics

Clocks

Table 20: **System Reference Clock Input Requirements**

Symbol	Description	Min	Typ	Max	Units
$T_{JTPSCLK}$	PS_CLK RMS clock jitter tolerance	–	–	±0.5	%
$T_{DCPSCLK}$	PS_CLK duty cycle	40	–	60	%
$T_{RFPSCLK}$	PS_CLK rise and fall time	–	4	–	ns
F_{PSCLK}	PS_CLK frequency	30	–	60	MHz

Notes:

1. Tested to commercial (C) and extended (E) temperature ranges only. See Temperature in Table 2.

Table 21: **PS PLL Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
T_{LOCK_PSPLL}	PLL maximum lock time	60	60	60	µs
F_{PSPLL_MAX}	PLL maximum output frequency	2000	1800	1600	MHz
F_{PSPLL_MIN}	PLL minimum output frequency	780	780	780	MHz

Resets

Table 22: **PS Reset Requirements**

Symbol	Description	Min	Typ	Max	Units
T_{PSPOR}	Required PS_POR_B assertion time(1)	100	–	–	µs
T_{PSRST}	Required PS_SRST_B assertion time	3	–	–	PS_CLK Clock Cycles

Notes:

1. PS_POR_B needs to be asserted low until PS supply voltages reach minimum levels.

PS Configuration

Table 23: **Processor Configuration Access Port Switching Characteristics**

Symbol	Description	Min	Typ	Max	Units
F_{PCAPCK}	Maximum processor configuration access port (PCAP) frequency	–	–	100	MHz

Table 28: **LPDDR2 Interface Switching Characteristics (400 Mb/s)(1)**

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
T_{DQDS}(2)	Output DQ to DQS skew	561	–	ps
T_{DQDH}(3)	Output DQS to DQ skew	852	–	ps
T_{DQSS}	Output clock to DQS skew	0.91	1.08	T_{CK}
T_{CACK}(4)	Command/address output setup time with respect to CLK	617	–	ps
T_{CKCA}(5)	Command/address output hold time with respect to CLK	918	–	ps

Notes:

1. Recommended V_{CCO_DDR} = 1.2V ±5%.
2. Measurement is taken from either the rising edge of DQ that crosses V_{IH}(AC) or the falling edge of DQ that crosses V_{IL}(AC) to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses V_{IL}(DC) or the falling edge of DQ that crosses V_{IH}(DC) to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IH}(AC) or the falling edge of CMD/ADDR that crosses V_{IL}(AC) to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IL}(DC) or the falling edge of CMD/ADDR that crosses V_{IH}(DC) to V_{REF} of CLK.

Table 29: **DDR2 Interface Switching Characteristics (800 Mb/s)(1)**

Symbol	Description	Min	Max	Units
$T_{DQVALID}$	Input data valid window	500	–	ps
T_{DQDS}(2)	Output DQ to DQS skew	147	–	ps
T_{DQDH}(3)	Output DQS to DQ skew	376	–	ps
T_{DQSS}	Output clock to DQS skew	–0.07	0.08	T_{CK}
T_{CACK}(4)	Command/address output setup time with respect to CLK	732	–	ps
T_{CKCA}(5)	Command/address output hold time with respect to CLK	938	–	ps

Notes:

1. Recommended V_{CCO_DDR} = 1.8V ±5%.
2. Measurement is taken from either the rising edge of DQ that crosses V_{IH}(AC) or the falling edge of DQ that crosses V_{IL}(AC) to V_{REF} of DQS.
3. Measurement is taken from either the rising edge of DQ that crosses V_{IL}(DC) or the falling edge of DQ that crosses V_{IH}(DC) to V_{REF} of DQS.
4. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IH}(AC) or the falling edge of CMD/ADDR that crosses V_{IL}(AC) to V_{REF} of CLK.
5. Measurement is taken from either the rising edge of CMD/ADDR that crosses V_{IL}(DC) or the falling edge of CMD/ADDR that crosses V_{IH}(DC) to V_{REF} of CLK.

Static Memory Controller

Table 31: **SMC Interface Delay Characteristics(1)(2)**

Symbol	Description	Min	Max	Units
$T_{NANDDOUT}$	NAND_IO output delay from last register to pad	4.12	6.45	ns
$T_{NANDALE}$	NAND_ALE output delay from last register to pad	5.08	6.33	ns
$T_{NANDCLE}$	NAND_CLE output delay from last register to pad	4.87	6.40	ns
T_{NANDWE}	NAND_WE_B output delay from last register to pad	4.69	5.89	ns
T_{NANDRE}	NAND_RE_B output delay from last register to pad	5.12	6.44	ns
T_{NANDCE}	NAND_CE_B output delay from last register to pad	4.68	5.89	ns
$T_{NANDDIN}$	NAND_IO setup time and input delay from pad to first register	1.48	3.09	ns
$T_{NANDBUSY}$	NAND_BUSY setup time and input delay from pad to first register	2.48	3.33	ns
T_{SRAMA}	SRAM_A output delay from last register to pad	3.94	5.73	ns
$T_{SRAMDOUT}$	SRAM_DQ output delay from last register to pad	4.66	6.45	ns
T_{SRAMCE}	SRAM_CE output delay from last register to pad	4.57	5.95	ns
T_{SRAMOE}	SRAM_OE_B output delay from last register to pad	4.79	6.13	ns
$T_{SRAMBLS}$	SRAM_BLS_B output delay from last register to pad	5.25	6.74	ns
T_{SRAMWE}	SRAM_WE_B output delay from last register to pad	5.12	6.48	ns
$T_{SRAMDIN}$	SRAM_DQ setup time and input delay from pad to first register	1.93	3.05	ns
$T_{SRAMWAIT}$	SRAM_WAIT setup time and input delay from pad to first register	2.26	3.15	ns

Notes:

1. All parameters do not include the package flight time and register controlled delays.
2. Refer to the ARM® PrimeCell® Static Memory Controller (PL350 series) Technical Reference Manual for more SMC timing details.

Quad-SPI Interfaces

Table 32: **Quad-SPI Interface Switching Characteristics**[1][2]

Symbol	Description	Min	Typical	Max	Units
Feedback Clock Enabled					
$T_{DCQSPICLK1}$	Quad-SPI clock duty cycle	44	–	56	%
$T_{QSPICKO1}$	Data and slave select output delay	–0.10	–	3.40	ns
$T_{QSPIDCK1}$	Input data setup time	2.00	–	–	ns
$T_{QSPICKD1}$	Input data hold time	1.30	–	–	ns
$T_{QSPISSCLK1}$	Slave select asserted to next clock edge	1	–	–	$F_{QSPI\_REF\_CLK}$ cycle
$T_{QSPICLKSS1}$	Clock edge to slave select deasserted	1	–	–	$F_{QSPI\_REF\_CLK}$ cycle
$F_{QSPICLK1}$	Quad-SPI device clock frequency	–	–	100[3]	MHz
Feedback Clock Disabled					
$T_{DCQSPICLK2}$	Quad-SPI clock duty cycle	44	–	56	%
$T_{QSPICKO2}$	Data and slave select output delay	–0.10	–	3.80	ns
$T_{QSPIDCK2}$	Input data setup time[4]	$11 - \frac{1}{F_{QSPI\_REF\_CLK}}$	–	–	ns
$T_{QSPICKD2}$	Input data hold time	$\frac{1}{2 \times F_{QSPICLK2}}$	–	–	ns
$T_{QSPISSCLK2}$	Slave select asserted to next clock edge	1	–	–	$F_{QSPI\_REF\_CLK}$ cycle
$T_{QSPICLKSS2}$	Clock edge to slave select deasserted	1	–	–	$F_{QSPI\_REF\_CLK}$ cycle
$F_{QSPICLK2}$	Quad-SPI device clock frequency	–	–	40	MHz
Feedback Clock Enabled or Disabled					
$F_{QSPI\_REF\_CLK}$	Quad-SPI reference clock frequency	–	–	200	MHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads, feedback clock pin has no load. Quad-SPI single slave select 4-bit I/O mode.
2. Dual slave select 4-bit stacked I/O configuration is not covered.
3. Requires appropriate component selection/board design.
4. Use 0 ns as the input data setup time when the calculated $T_{QSPIDCK2}$ value is negative.

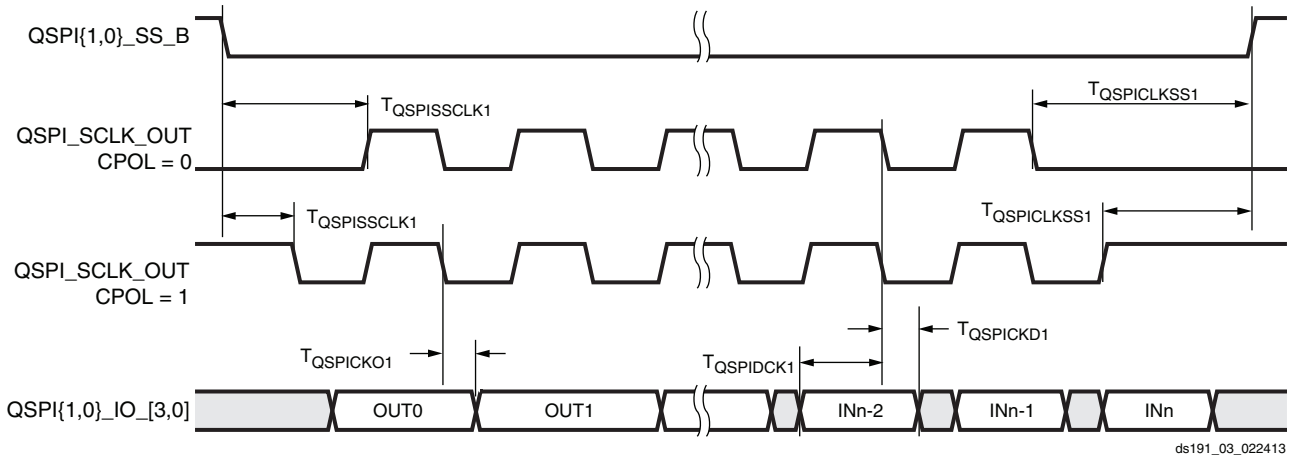

Figure 3: **Quad-SPI Interface (Feedback Clock Enabled) Timing Diagram**

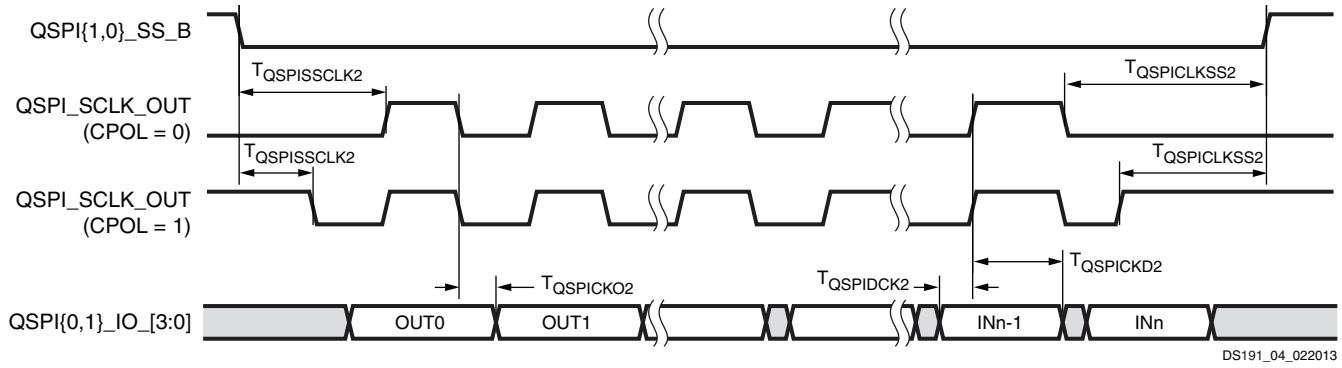

Figure 4: **Quad-SPI Interface (Feedback Clock Disabled) Timing Diagram**

ULPI Interfaces

Table 33: **ULPI Interface Clock Receiving Mode Switching Characteristics**(1)(2)

Symbol	Description	Min	Typ	Max	Units
$T_{ULPIDCK}$	Input setup to ULPI clock, all inputs	3.00	–	–	ns
$T_{ULPICKD}$	Input hold to ULPI clock, all inputs	1.00	–	–	ns
$T_{ULPICKO}$	ULPI clock to output valid, all outputs	1.70	–	8.86	ns
$F_{ULPICLK}$	ULPI device clock frequency	–	60	–	MHz

Notes:

1. Test conditions: LVCMOS33, slow slew rate, 8 mA drive strength, 15 pF loads, 60 MHz device clock frequency.
2. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.

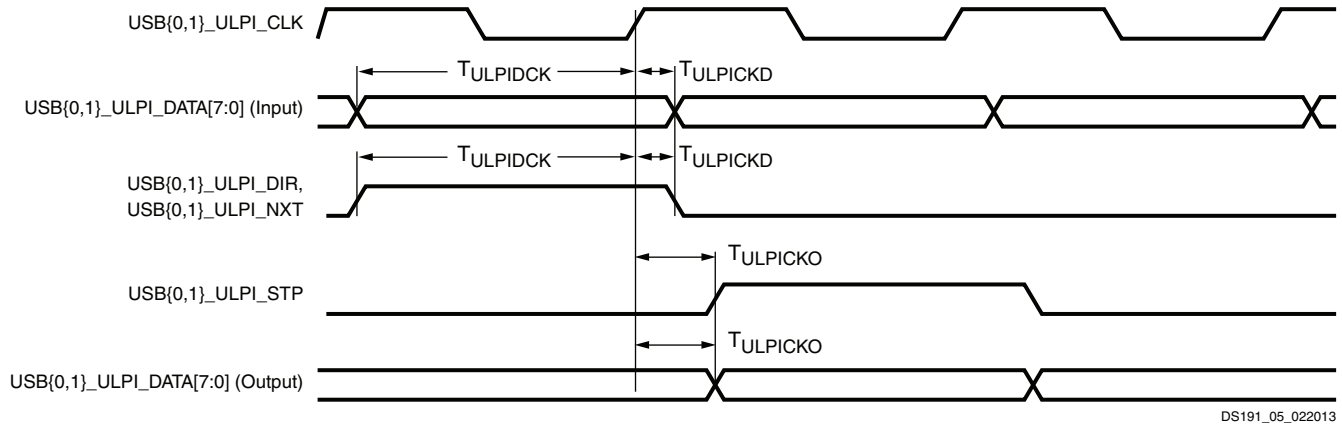

Figure 5: **ULPI Interface Timing Diagram**

RGMII and MDIO Interfaces

Table 34: **RGMII and MDIO Interface Switching Characteristics(1)(2)(3)**

Symbol	Description	Min	Typ	Max	Units
$T_{DCGETXCLK}$	Transmit clock duty cycle	45	–	55	%
$T_{GEMTXCKO}$	RGMII_TX_D[3:0], RGMII_TX_CTL output clock to out time	–0.50	–	0.50	ns
$T_{GEMRXDCK}$	RGMII_RX_D[3:0], RGMII_RX_CTL input setup time	0.80	–	–	ns
$T_{GEMRXCKD}$	RGMII_RX_D[3:0], RGMII_RX_CTL input hold time	0.80	–	–	ns
$T_{MDIOCLK}$	MDC output clock period	400	–	–	ns
$T_{MDIOCKH}$	MDC clock High time	160	–	–	ns
$T_{MDIOCKL}$	MDC clock Low time	160	–	–	ns
$T_{MDIODCK}$	MDIO input data setup time	80	–	–	ns
$T_{MDIOCKD}$	MDIO input data hold time	0	–	–	ns
$T_{MDIOCKO}$	MDIO data output delay	–20	–	170	ns
$F_{GETXCLK}$	RGMII_TX_CLK transmit clock frequency	–	125	–	MHz
$F_{GERXCLK}$	RGMII_RX_CLK receive clock frequency	–	125	–	MHz
$F_{ENET\_REF\_CLK}$	Ethernet reference clock frequency	–	125	–	MHz

Notes:

1. Test conditions: LVCMOS25, fast slew rate, 8 mA drive strength, 15 pF loads. Values in this table are specified during 1000 Mb/s operation.
2. LVCMOS25 slow slew rate and LVCMOS33 are not supported.
3. All timing values assume an ideal external input clock. Actual design system timing budgets should account for additional external clock jitter.

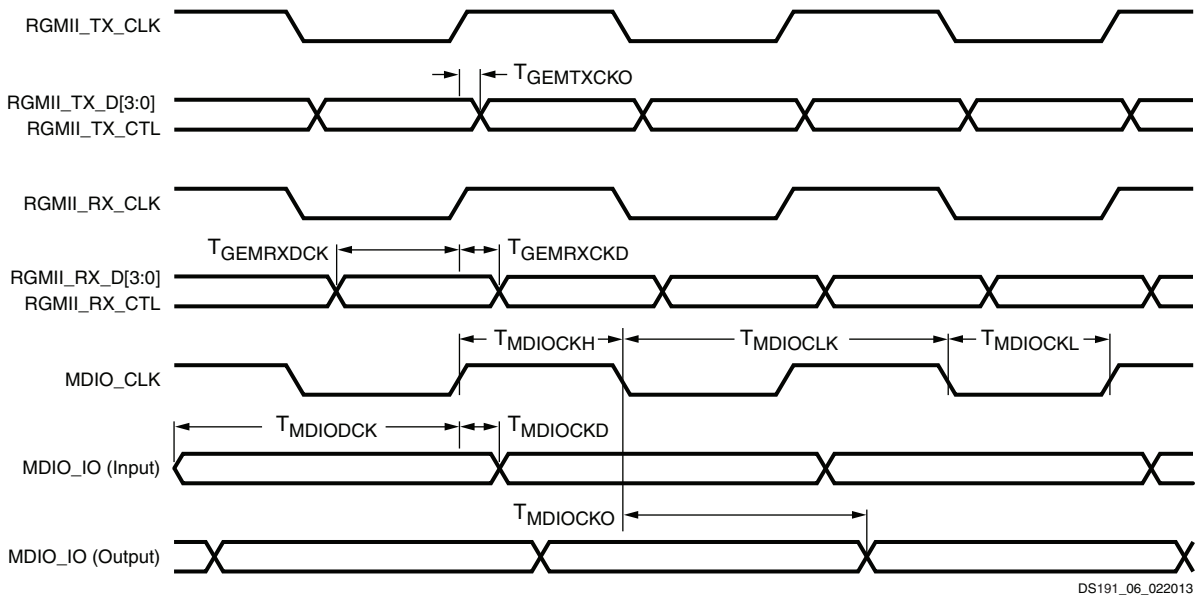

Figure 6: **RGMII Interface Timing Diagram**

PS-PL Interface

Table 48: **PS-PL Interface Performance**

Symbol	Description	Min	Typical	Max	Units
$F_{EMIOGEMCLK}$	EMIO gigabit Ethernet controller maximum frequency	–	–	125	MHz
$F_{EMIOSDCLK}$	EMIO SD controller maximum frequency	–	–	25	MHz
$F_{EMIOSPICLK}$	EMIO SPI controller maximum frequency	–	–	25	MHz
$F_{EMIOJTAGCLK}$	EMIO JTAG controller maximum frequency	–	–	20	MHz
$F_{EMIOTRACECLK}$	EMIO trace controller maximum frequency	–	–	125	MHz
F_{FTMCLK}	Fabric trace monitor maximum frequency	–	–	125	MHz
$F_{EMIODMACLK}$	DMA maximum frequency	–	–	100	MHz

PL Performance Characteristics

This section provides the performance characteristics of some common functions and designs implemented in the PL. The numbers reported here are worst-case values; they have all been fully characterized. These values are subject to the same guidelines as the AC Switching Characteristics, page 13. In each table, the I/O bank type is either High Performance (HP) or High Range (HR).

Table 49: **PL Networking Applications Interface Performances**

Description	I/O Bank Type	Speed Grade			Units
		-3	-2	-1	
SDR LVDS transmitter (using OSERDES; DATA_WIDTH = 4 to 8)	HR	710	710	625	Mb/s
	HP	710	710	625	Mb/s
DDR LVDS transmitter (using OSERDES; DATA_WIDTH = 4 to 14)	HR	1250	1250	950	Mb/s
	HP	1600	1400	1250	Mb/s
SDR LVDS receiver (SFI-4.1)(1)	HR	710	710	625	Mb/s
	HP	710	710	625	Mb/s
DDR LVDS receiver (SPI-4.2)(1)	HR	1250	1250	950	Mb/s
	HP	1600	1400	1250	Mb/s

Notes:

1. LVDS receivers are typically bounded with certain applications where specific dynamic phase-alignment (DPA) algorithms dominate deterministic performance.

Table 53: **1.8V IOB High Performance (HP) Switching Characteristics**

I/O Standard	T_{IOPI}			T_{IOOP}			T_{IOTP}			Units
	Speed Grade			Speed Grade			Speed Grade			
	-3	-2	-1	-3	-2	-1	-3	-2	-1	
LVDS	0.75	0.79	0.92	1.05	1.17	1.24	1.68	1.92	2.06	ns
HSUL_12	0.69	0.72	0.82	1.65	1.84	2.05	2.29	2.59	2.87	ns
DIFF_HSUL_12	0.69	0.72	0.82	1.65	1.84	2.05	2.29	2.59	2.87	ns
HSTL_I_S	0.68	0.72	0.82	1.15	1.28	1.38	1.79	2.03	2.20	ns
HSTL_II_S	0.68	0.72	0.82	1.05	1.17	1.26	1.69	1.93	2.08	ns
HSTL_I_18_S	0.70	0.72	0.82	1.12	1.24	1.34	1.75	2.00	2.16	ns
HSTL_II_18_S	0.70	0.72	0.82	1.06	1.18	1.26	1.70	1.94	2.08	ns
HSTL_I_12_S	0.68	0.72	0.82	1.14	1.27	1.37	1.78	2.02	2.20	ns
HSTL_I_DCI_S	0.68	0.72	0.82	1.11	1.23	1.33	1.74	1.99	2.15	ns
HSTL_II_DCI_S	0.68	0.72	0.82	1.05	1.17	1.26	1.69	1.93	2.08	ns
HSTL_II_T_DCI_S	0.70	0.72	0.82	1.15	1.28	1.38	1.78	2.03	2.20	ns
HSTL_I_DCI_18_S	0.70	0.72	0.82	1.11	1.23	1.33	1.74	1.99	2.15	ns
HSTL_II_DCI_18_S	0.70	0.72	0.82	1.05	1.16	1.24	1.69	1.92	2.06	ns
HSTL_II _T_DCI_18_S	0.70	0.72	0.82	1.11	1.23	1.33	1.74	1.99	2.15	ns
DIFF_HSTL_I_S	0.75	0.79	0.92	1.15	1.28	1.38	1.79	2.03	2.20	ns
DIFF_HSTL_II_S	0.75	0.79	0.92	1.05	1.17	1.26	1.69	1.93	2.08	ns
DIFF_HSTL_I_DCI_S	0.75	0.79	0.92	1.15	1.28	1.38	1.78	2.03	2.20	ns
DIFF_HSTL_II_DCI_S	0.75	0.79	0.92	1.05	1.17	1.26	1.69	1.93	2.08	ns
DIFF_HSTL_I_18_S	0.75	0.79	0.92	1.12	1.24	1.34	1.75	2.00	2.16	ns
DIFF_HSTL_II_18_S	0.75	0.79	0.92	1.06	1.18	1.26	1.70	1.94	2.08	ns
DIFF_HSTL_I_DCI_18_S	0.75	0.79	0.92	1.11	1.23	1.33	1.74	1.99	2.15	ns
DIFF_HSTL_II_DCI_18_S	0.75	0.79	0.92	1.05	1.16	1.24	1.69	1.92	2.06	ns
DIFF_HSTL_II _T_DCI_18_S	0.75	0.79	0.92	1.11	1.23	1.33	1.74	1.99	2.15	ns
HSTL_I_F	0.68	0.72	0.82	1.02	1.14	1.22	1.66	1.90	2.04	ns
HSTL_II_F	0.68	0.72	0.82	0.97	1.08	1.15	1.61	1.84	1.97	ns
HSTL_I_18_F	0.70	0.72	0.82	1.04	1.16	1.24	1.68	1.91	2.06	ns
HSTL_II_18_F	0.70	0.72	0.82	0.98	1.09	1.16	1.62	1.85	1.98	ns
HSTL_I_12_F	0.68	0.72	0.82	1.02	1.13	1.21	1.65	1.88	2.03	ns
HSTL_I_DCI_F	0.68	0.72	0.82	1.04	1.16	1.24	1.67	1.91	2.06	ns
HSTL_II_DCI_F	0.68	0.72	0.82	0.97	1.08	1.15	1.61	1.84	1.97	ns
HSTL_II_T_DCI_F	0.70	0.72	0.82	1.02	1.14	1.22	1.66	1.90	2.04	ns
HSTL_I_DCI_18_F	0.70	0.72	0.82	1.04	1.16	1.24	1.67	1.91	2.06	ns
HSTL_II_DCI_18_F	0.70	0.72	0.82	0.98	1.09	1.16	1.61	1.85	1.98	ns
HSTL_II _T_DCI_18_F	0.70	0.72	0.82	1.04	1.16	1.24	1.67	1.91	2.06	ns
DIFF_HSTL_I_F	0.75	0.79	0.92	1.02	1.14	1.22	1.66	1.90	2.04	ns
DIFF_HSTL_II_F	0.75	0.79	0.92	0.97	1.08	1.15	1.61	1.84	1.97	ns
DIFF_HSTL_I_DCI_F	0.75	0.79	0.92	1.02	1.14	1.22	1.66	1.90	2.04	ns
DIFF_HSTL_II_DCI_F	0.75	0.79	0.92	0.97	1.08	1.15	1.61	1.84	1.97	ns

Table 53: **1.8V IOB High Performance (HP) Switching Characteristics *(Cont'd)***

I/O Standard	T_{IOPI}			T_{IOOP}			T_{IOTP}			Units
	Speed Grade			Speed Grade			Speed Grade			
	-3	-2	-1	-3	-2	-1	-3	-2	-1	
LVDCI_15	0.59	0.62	0.73	1.98	2.23	2.58	2.62	2.99	3.40	ns
LVDCI_DV2_18	0.47	0.50	0.60	1.99	2.15	2.34	2.62	2.90	3.17	ns
LVDCI_DV2_15	0.59	0.62	0.73	1.98	2.23	2.58	2.62	2.99	3.40	ns
HSLVDCI_18	0.68	0.72	0.82	1.99	2.15	2.35	2.62	2.91	3.17	ns
HSLVDCI_15	0.68	0.72	0.82	1.98	2.23	2.58	2.62	2.99	3.40	ns
SSTL18_I_S	0.68	0.72	0.82	1.02	1.15	1.24	1.66	1.90	2.07	ns
SSTL18_II_S	0.68	0.72	0.82	1.17	1.29	1.37	1.81	2.05	2.19	ns
SSTL18_I_DCI_S	0.68	0.72	0.82	0.92	1.06	1.17	1.56	1.82	1.99	ns
SSTL18_II_DCI_S	0.68	0.72	0.82	0.88	0.98	1.08	1.51	1.74	1.90	ns
SSTL18_II_T_DCI_S	0.68	0.72	0.82	0.92	1.06	1.17	1.56	1.82	1.99	ns
SSTL15_S	0.68	0.72	0.82	0.94	1.06	1.15	1.58	1.82	1.97	ns
SSTL15_DCI_S	0.68	0.72	0.82	0.94	1.06	1.15	1.57	1.82	1.97	ns
SSTL15_T_DCI_S	0.68	0.72	0.82	0.94	1.06	1.15	1.57	1.82	1.97	ns
SSTL135_S	0.69	0.72	0.82	0.97	1.10	1.19	1.60	1.85	2.01	ns
SSTL135_DCI_S	0.69	0.72	0.82	0.97	1.09	1.19	1.60	1.85	2.01	ns
SSTL135_T_DCI_S	0.69	0.72	0.82	0.97	1.09	1.19	1.60	1.85	2.01	ns
SSTL12_S	0.69	0.72	0.82	0.96	1.09	1.18	1.60	1.84	2.00	ns
SSTL12_DCI_S	0.69	0.72	0.82	1.03	1.17	1.27	1.66	1.92	2.09	ns
SSTL12_T_DCI_S	0.69	0.72	0.82	1.03	1.17	1.27	1.66	1.92	2.09	ns
DIFF_SSTL18_I_S	0.75	0.79	0.92	1.02	1.15	1.24	1.66	1.90	2.07	ns
DIFF_SSTL18_II_S	0.75	0.79	0.92	1.17	1.29	1.37	1.81	2.05	2.19	ns
DIFF_SSTL18_I_DCI_S	0.75	0.79	0.92	0.92	1.06	1.17	1.56	1.82	1.99	ns
DIFF_SSTL18_II_DCI_S	0.75	0.79	0.92	0.88	0.98	1.08	1.51	1.74	1.90	ns
DIFF_SSTL18_II_T_DCI_S	0.75	0.79	0.92	0.92	1.06	1.17	1.56	1.82	1.99	ns
DIFF_SSTL15_S	0.68	0.72	0.82	0.94	1.06	1.15	1.58	1.82	1.97	ns
DIFF_SSTL15_DCI_S	0.68	0.72	0.82	0.94	1.06	1.15	1.57	1.82	1.97	ns
DIFF_SSTL15_T_DCI_S	0.68	0.72	0.82	0.94	1.06	1.15	1.57	1.82	1.97	ns
DIFF_SSTL135_S	0.69	0.72	0.82	0.97	1.10	1.19	1.60	1.85	2.01	ns
DIFF_SSTL135_DCI_S	0.69	0.72	0.82	0.97	1.09	1.19	1.60	1.85	2.01	ns
DIFF_SSTL135_T_DCI_S	0.69	0.72	0.82	0.97	1.09	1.19	1.60	1.85	2.01	ns
DIFF_SSTL12_S	0.69	0.72	0.82	0.96	1.09	1.18	1.60	1.84	2.00	ns
DIFF_SSTL12_DCI_S	0.69	0.72	0.82	1.03	1.17	1.27	1.66	1.92	2.09	ns
DIFF_SSTL12_T_DCI_S	0.69	0.72	0.82	1.03	1.17	1.27	1.66	1.92	2.09	ns
SSTL18_I_F	0.68	0.72	0.82	0.94	1.06	1.15	1.58	1.82	1.97	ns
SSTL18_II_F	0.68	0.72	0.82	0.97	1.09	1.16	1.61	1.84	1.99	ns
SSTL18_I_DCI_F	0.68	0.72	0.82	0.89	1.02	1.10	1.53	1.77	1.92	ns
SSTL18_II_DCI_F	0.68	0.72	0.82	0.89	1.02	1.10	1.53	1.77	1.92	ns
SSTL18_II_T_DCI_F	0.68	0.72	0.82	0.89	1.02	1.10	1.53	1.77	1.92	ns

Input Serializer/Deserializer Switching Characteristics

Table 57: **ISERDES Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Setup/Hold for Control Lines					
$T_{ISCCK\_BITSLIP}$/ $T_{ISCKC\_BITSLIP}$	BITSLIP pin setup/hold with respect to CLKDIV	0.01/0.12	0.02/0.13	0.02/0.15	ns
T_{ISCCK_CE} / T_{ISCKC_CE}(2)	CE pin setup/hold with respect to CLK (for CE1)	0.39/–0.02	0.44/–0.02	0.63/–0.02	ns
T_{ISCCK_CE2} / T_{ISCKC_CE2}(2)	CE pin setup/hold with respect to CLKDIV (for CE2)	–0.12/0.29	–0.12/0.31	–0.12/0.35	ns
Setup/Hold for Data Lines					
T_{ISDCK_D} /T_{ISCKD_D}	D pin setup/hold with respect to CLK	–0.02/0.11	–0.02/0.12	–0.02/0.15	ns
T_{ISDCK_DDLY} /T_{ISCKD_DDLY}	DDLY pin setup/hold with respect to CLK (using IDELAY)(1)	–0.02/0.11	–0.02/0.12	–0.02/0.15	ns
$T_{ISDCK\_D\_DDR}$ /$T_{ISCKD\_D\_DDR}$	D pin setup/hold with respect to CLK at DDR mode	–0.02/0.11	–0.02/0.12	–0.02/0.15	ns
$T_{ISDCK\_DDLY\_DDR}$/ $T_{ISCKD\_DDLY\_DDR}$	D pin setup/hold with respect to CLK at DDR mode (using IDELAY)(1)	0.11/0.11	0.12/0.12	0.15/0.15	ns
Sequential Delays					
T_{ISCKO_Q}	CLKDIV to out at Q pin	0.46	0.47	0.58	ns
Propagation Delays					
T_{ISDO_DO}	D input to DO output pin	0.09	0.10	0.12	ns

Notes:

1. Recorded at 0 tap value.
2. T_{ISCCK_CE2} and T_{ISCKC_CE2} are reported as T_{ISCCK_CE}/T_{ISCKC_CE} in TRACE report.

Output Serializer/Deserializer Switching Characteristics

Table 58: **OSERDES Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Setup/Hold					
T_{OSDCK_D}/T_{OSCKD_D}	D input setup/hold with respect to CLKDIV	0.37/0.02	0.40/0.02	0.55/0.02	ns
T_{OSDCK_T}/T_{OSCKD_T}(1)	T input setup/hold with respect to CLK	0.49/–0.15	0.56/–0.15	0.68/–0.15	ns
T_{OSDCK_T2}/T_{OSCKD_T2}(1)	T input setup/hold with respect to CLKDIV	0.27/–0.15	0.30/–0.15	0.34/–0.15	ns
T_{OSCCK_OCE}/T_{OSCKC_OCE}	OCE input setup/hold with respect to CLK	0.28/0.03	0.29/0.03	0.45/0.03	ns
T_{OSCCK_S}	SR (reset) input setup with respect to CLKDIV	0.41	0.46	0.75	ns
T_{OSCCK_TCE}/T_{OSCKC_TCE}	TCE input setup/hold with respect to CLK	0.28/0.01	0.30/0.01	0.45/0.01	ns
Sequential Delays					
T_{OSCKO_OQ}	Clock to out from CLK to OQ	0.35	0.37	0.42	ns
T_{OSCKO_TQ}	Clock to out from CLK to TQ	0.41	0.43	0.49	ns
Combinatorial					
T_{OSDO_TTQ}	T input to TQ out	0.73	0.81	0.97	ns

Notes:

1. T_{OSDCK_T2} and T_{OSCKD_T2} are reported as T_{OSDCK_T}/T_{OSCKD_T} in TRACE report.

CLB Distributed RAM Switching Characteristics (SLICEM Only)

Table 62: **CLB Distributed RAM Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Sequential Delays					
T_{SHCKO}	Clock to A – B outputs	0.68	0.70	0.85	ns, Max
T_{SHCKO_1}	Clock to AMUX – BMUX outputs	0.91	0.95	1.15	ns, Max
Setup and Hold Times Before/After Clock CLK					
T_{DS_LRAM}/T_{DH_LRAM}	A – D inputs to CLK	0.45/0.23	0.45/0.24	0.54/0.27	ns, Min
T_{AS_LRAM}/T_{AH_LRAM}	Address An inputs to clock	0.13/0.50	0.14/0.50	0.17/0.58	ns, Min
	Address An inputs through MUXs and/or carry logic to clock	0.40/0.16	0.42/0.17	0.52/0.23	ns, Min
T_{WS_LRAM}/T_{WH_LRAM}	WE input to clock	0.29/0.09	0.30/0.09	0.36/0.09	ns, Min
$T_{CECK\_LRAM}/T_{CKCE\_LRAM}$	CE input to CLK	0.29/0.09	0.30/0.09	0.37/0.09	ns, Min
Clock CLK					
T_{MPW_LRAM}	Minimum pulse width	0.68	0.77	0.91	ns, Min
T_{MCP}	Minimum clock period	1.35	1.54	1.82	ns, Min

Notes:

1. A Zero “0” hold time listing indicates no hold time or a negative hold time.
2. T_{SHCKO} also represents the CLK to XMUX output. Refer to TRACE report for the CLK to XMUX path.

CLB Shift Register Switching Characteristics (SLICEM Only)

Table 63: **CLB Shift Register Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Sequential Delays					
T_{REG}	Clock to A – D outputs	0.96	0.98	1.20	ns, Max
T_{REG_MUX}	Clock to AMUX – DMUX output	1.19	1.23	1.50	ns, Max
T_{REG_M31}	Clock to DMUX output via M31 output	0.89	0.91	1.10	ns, Max
Setup and Hold Times Before/After Clock CLK					
$T_{WS\_SHFREG}/T_{WH\_SHFREG}$	WE input	0.26/0.09	0.27/0.09	0.33/0.09	ns, Min
$T_{CECK\_SHFREG}/T_{CKCE\_SHFREG}$	CE input to CLK	0.27/0.09	0.28/0.09	0.33/0.09	ns, Min
$T_{DS\_SHFREG}/T_{DH\_SHFREG}$	A – D inputs to CLK	0.28/0.26	0.28/0.26	0.33/0.30	ns, Min
Clock CLK					
T_{MPW_SHFREG}	Minimum pulse width	0.55	0.65	0.78	ns, Min

Notes:

1. A Zero “0” hold time listing indicates no hold time or a negative hold time.

Table 64: **Block RAM and FIFO Switching Characteristics *(Cont'd)***

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Reset Delays					
T_{RCO_FLAGS}	Reset RST to FIFO flags/pointers(10)	0.76	0.83	0.93	ns, Max
$T_{RREC\_RST}/T_{RREM\_RST}$	FIFO reset recovery and removal timing(11)	1.59/–0.68	1.76/–0.68	2.01/–0.68	ns, Max
Maximum Frequency					
$F_{MAX\_BRAM\_WF\_NC}$	Block RAM (Write first and No change modes) When not in SDP RF mode	601.32	543.77	458.09	MHz
$F_{MAX\_BRAM\_RF\_PERFORMANCE}$	Block RAM (Read first, Performance mode) When in SDP RF mode but no address overlap between port A and port B	601.32	543.77	458.09	MHz
$F_{MAX\_BRAM\_RF\_DELAYED\_WRITE}$	Block RAM (Read first, Delayed_write mode) When in SDP RF mode and there is possibility of overlap between port A and port B addresses	528.26	477.33	400.80	MHz
$F_{MAX\_CAS\_WF\_NC}$	Block RAM Cascade (Write first, No change mode) When cascade but not in RF mode	551.27	493.93	408.00	MHz
$F_{MAX\_CAS\_RF\_PERFORMANCE}$	Block RAM Cascade (Read first, Performance mode) When in cascade with RF mode and no possibility of address overlap/one port is disabled	551.27	493.93	408.00	MHz
$F_{MAX\_CAS\_RF\_DELAYED\_WRITE}$	When in cascade RF mode and there is a possibility of address overlap between port A and port B	478.24	427.35	350.88	MHz
F_{MAX_FIFO}	FIFO in all modes without ECC	601.32	543.77	458.09	MHz
F_{MAX_ECC}	Block RAM and FIFO in ECC configuration	484.26	430.85	351.12	MHz

Notes:

1. TRACE will report all of these parameters as T_{RCKO_DO}.
2. T_{RCKO_DOR} includes T_{RCKO_DOW}, T_{RCKO_DOPR}, and T_{RCKO_DOPW} as well as the B port equivalent timing parameters.
3. These parameters also apply to synchronous FIFO with DO_REG = 0.
4. T_{RCKO_DO} includes T_{RCKO_DOP} as well as the B port equivalent timing parameters.
5. These parameters also apply to multirate (asynchronous) and synchronous FIFO with DO_REG = 1.
6. T_{RCKO_FLAGS} includes the following parameters: T_{RCKO_AEMPTY}, T_{RCKO_AFULL}, T_{RCKO_EMPTY}, T_{RCKO_FULL}, T_{RCKO_RDERR}, T_{RCKO_WRERR}.
7. $T_{RCKO\_POINTERS}$ includes both $T_{RCKO\_RDCOUNT}$ and $T_{RCKO\_WRCOUNT}$.
8. The ADDR setup and hold must be met when EN is asserted (even when WE is deasserted). Otherwise, block RAM data corruption is possible.
9. These parameters include both A and B inputs as well as the parity inputs of A and B.
10. T_{RCO_FLAGS} includes the following flags: AEMPTY, AFULL, EMPTY, FULL, RDERR, WRERR, RDCOUNT, and WRCOUNT.
11. RDEN and WREN must be held Low prior to and during reset. The FIFO reset must be asserted for at least five positive clock edges of the slowest clock (WRCLK or RDCLK).

DSP48E1 Switching Characteristics

Table 65: **DSP48E1 Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Setup and Hold Times of Data/Control Pins to the Input Register Clock					
$T_{DSPDCK\_A\_AREG}$/ $T_{DSPCKD\_A\_AREG}$	A input to A register CLK	0.24/0.12	0.27/0.14	0.31/0.16	ns
$T_{DSPDCK\_B\_BREG}$/$T_{DSPCKD\_B\_BREG}$	B input to B register CLK	0.28/0.13	0.32/0.14	0.39/0.15	ns
$T_{DSPDCK\_C\_CREG}$/$T_{DSPCKD\_C\_CREG}$	C input to C register CLK	0.15/0.15	0.17/0.17	0.20/0.20	ns
$T_{DSPDCK\_D\_DREG}$/$T_{DSPCKD\_D\_DREG}$	D input to D register CLK	0.21/0.19	0.27/0.22	0.35/0.26	ns
$T_{DSPDCK\_ACIN\_AREG}$/$T_{DSPCKD\_ACIN\_AREG}$	ACIN input to A register CLK	0.21/0.12	0.24/0.14	0.27/0.16	ns
$T_{DSPDCK\_BCIN\_BREG}$/$T_{DSPCKD\_BCIN\_BREG}$	BCIN input to B register CLK	0.22/0.13	0.25/0.14	0.30/0.15	ns
Setup and Hold Times of Data Pins to the Pipeline Register Clock					
$T_{DSPDCK\_\{A, B\}\_MREG\_MULT}$/ $T_{DSPCKD\_B\_MREG\_MULT}$	{A, B,} input to M register CLK using multiplier	2.04/–0.01	2.34/–0.01	2.79/–0.01	ns
$T_{DSPDCK\_\{A, B\}\_ADREG}$/ $T_{DSPCKD\_ D\_ADREG}$	{A, D} input to AD register CLK	1.09/–0.02	1.25/–0.02	1.49/–0.02	ns
Setup and Hold Times of Data/Control Pins to the Output Register Clock					
$T_{DSPDCK\_\{A, B\}\_PREG\_MULT}$/ $T_{DSPCKD\_\{A, B\} \_PREG\_MULT}$	{A, B,} input to P register CLK using multiplier	3.41/–0.24	3.90/–0.24	4.64/–0.24	ns
$T_{DSPDCK\_D\_PREG\_MULT}$/ $T_{DSPCKD\_D\_PREG\_MULT}$	D input to P register CLK using multiplier	3.33/–0.62	3.81/–0.62	4.53/–0.62	ns
$T_{DSPDCK\_\{A, B\} \_PREG}$/ $T_{DSPCKD\_\{A, B\} \_PREG}$	A or B input to P register CLK not using multiplier	1.47/–0.24	1.68/–0.24	2.00/–0.24	ns
$T_{DSPDCK\_C\_PREG}$/ $T_{DSPCKD\_C\_PREG}$	C input to P register CLK not using multiplier	1.30/–0.22	1.49/–0.22	1.78/–0.22	ns
$T_{DSPDCK\_PCIN\_PREG}$/ $T_{DSPCKD\_PCIN\_PREG}$	PCIN input to P register CLK	1.12/–0.13	1.28/–0.13	1.52/–0.13	ns
Setup and Hold Times of the CE Pins					
$T_{DSPDCK\_\{CEA;CEB\}\_\{AREG;BREG\}}$/ $T_{DSPCKD\_\{CEA;CEB\}\_\{AREG;BREG\}}$	{CEA; CEB} input to {A; B} register CLK	0.30/0.05	0.36/0.06	0.44/0.09	ns
$T_{DSPDCK\_CEC\_CREG}$/ $T_{DSPCKD\_CEC\_CREG}$	CEC input to C register CLK	0.24/0.08	0.29/0.09	0.36/0.11	ns
$T_{DSPDCK\_CED\_DREG}$/ $T_{DSPCKD\_CED\_DREG}$	CED input to D register CLK	0.31/–0.02	0.36/–0.02	0.44/–0.02	ns
$T_{DSPDCK\_CEM\_MREG}$/ $T_{DSPCKD\_CEM\_MREG}$	CEM input to M register CLK	0.26/0.15	0.29/0.17	0.33/0.20	ns
$T_{DSPDCK\_CEP\_PREG}$/ $T_{DSPCKD\_CEP\_PREG}$	CEP input to P register CLK	0.31/0.01	0.36/0.01	0.45/0.01	ns
Setup and Hold Times of the RST Pins					
$T_{DSPDCK\_\{RSTA; RSTB\}\_\{AREG; BREG\}}$/ $T_{DSPCKD\_\{RSTA; RSTB\}\_\{AREG; BREG\}}$	{RSTA, RSTB} input to {A, B} register CLK	0.34/0.10	0.39/0.11	0.47/0.13	ns
$T_{DSPDCK\_RSTC\_CREG}$/ $T_{DSPCKD\_RSTC\_CREG}$	RSTC input to C register CLK	0.06/0.22	0.07/0.24	0.08/0.26	ns
$T_{DSPDCK\_RSTD\_DREG}$/ $T_{DSPCKD\_RSTD\_DREG}$	RSTD input to D register CLK	0.37/0.06	0.42/0.06	0.50/0.07	ns
$T_{DSPDCK\_RSTM\_MREG}$/ $T_{DSPCKD\_RSTM\_MREG}$	RSTM input to M register CLK	0.18/0.18	0.20/0.21	0.23/0.24	ns
$T_{DSPDCK\_RSTP\_PREG}$/ $T_{DSPCKD\_RSTP\_PREG}$	RSTP input to P register CLK	0.24/0.01	0.26/0.01	0.30/0.01	ns
Combinatorial Delays from Input Pins to Output Pins					
$T_{DSPDO\_A\_CARRYOUT\_MULT}$	A input to CARRYOUT output using multiplier	3.21	3.69	4.39	ns
$T_{DSPDO\_D\_P\_MULT}$	D input to P output using multiplier	3.15	3.61	4.30	ns
$T_{DSPDO\_A\_P}$	A input to P output not using multiplier	1.30	1.48	1.76	ns
$T_{DSPDO\_C\_P}$	C input to P output	1.13	1.30	1.55	ns

Table 65: **DSP48E1 Switching Characteristics *(Cont'd)***

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Combinatorial Delays from Input Pins to Cascading Output Pins					
$T_{DSPDO\_\{A; B\}\_\{ACOUT; BCOUT\}}$	{A, B} input to {ACOUT, BCOUT} output	0.47	0.53	0.63	ns
$T_{DSPDO\_\{A, B\}\_CARRYCASCOUT\_MULT}$	{A, B} input to CARRYCASCOUT output using multiplier	3.44	3.94	4.69	ns
$T_{DSPDO\_D\_CARRYCASCOUT\_MULT}$	D input to CARRYCASCOUT output using multiplier	3.36	3.85	4.58	ns
$T_{DSPDO\_\{A, B\}\_CARRYCASCOUT}$	{A, B} input to CARRYCASCOUT output not using multiplier	1.50	1.72	2.04	ns
$T_{DSPDO\_C\_CARRYCASCOUT}$	C input to CARRYCASCOUT output	1.34	1.53	1.83	ns
Combinatorial Delays from Cascading Input Pins to All Output Pins					
$T_{DSPDO\_ACIN\_P\_MULT}$	ACIN input to P output using multiplier	3.09	3.55	4.24	ns
$T_{DSPDO\_ACIN\_P}$	ACIN input to P output not using multiplier	1.16	1.33	1.59	ns
$T_{DSPDO\_ACIN\_ACOUT}$	ACIN input to ACOUT output	0.32	0.37	0.45	ns
$T_{DSPDO\_ACIN\_CARRYCASCOUT\_MULT}$	ACIN input to CARRYCASCOUT output using multiplier	3.30	3.79	4.52	ns
$T_{DSPDO\_ACIN\_CARRYCASCOUT}$	ACIN input to CARRYCASCOUT output not using multiplier	1.37	1.57	1.87	ns
$T_{DSPDO\_PCIN\_P}$	PCIN input to P output	0.94	1.08	1.29	ns
$T_{DSPDO\_PCIN\_CARRYCASCOUT}$	PCIN input to CARRYCASCOUT output	1.15	1.32	1.57	ns
Clock to Outs from Output Register Clock to Output Pins					
$T_{DSPCKO\_P\_PREG}$	CLK PREG to P output	0.33	0.35	0.39	ns
$T_{DSPCKO\_CARRYCASCOUT\_PREG}$	CLK PREG to CARRYCASCOUT output	0.44	0.50	0.59	ns
Clock to Outs from Pipeline Register Clock to Output Pins					
$T_{DSPCKO\_P\_MREG}$	CLK MREG to P output	1.42	1.64	1.96	ns
$T_{DSPCKO\_CARRYCASCOUT\_MREG}$	CLK MREG to CARRYCASCOUT output	1.63	1.87	2.24	ns
$T_{DSPCKO\_P\_ADREG\_MULT}$	CLK ADREG to P output using multiplier	2.30	2.63	3.13	ns
$T_{DSPCKO\_CARRYCASCOUT\_ADREG\_MULT}$	CLK ADREG to CARRYCASCOUT output using multiplier	2.51	2.87	3.41	ns
Clock to Outs from Input Register Clock to Output Pins					
$T_{DSPCKO\_P\_AREG\_MULT}$	CLK AREG to P output using multiplier	3.34	3.83	4.55	ns
$T_{DSPCKO\_P\_BREG}$	CLK BREG to P output not using multiplier	1.39	1.59	1.88	ns
$T_{DSPCKO\_P\_CREG}$	CLK CREG to P output not using multiplier	1.43	1.64	1.95	ns
$T_{DSPCKO\_P\_DREG\_MULT}$	CLK DREG to P output using multiplier	3.32	3.80	4.51	ns

Table 81: **Data Input Setup and Hold Times Relative to a Forwarded Clock Input Pin Using BUFIO**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
T_{PSCS}/T_{PHCS}	Setup/hold of I/O clock for HR I/O banks	–0.36/1.36	–0.36/1.50	–0.36/1.70	ns
	Setup/hold of I/O clock for HP I/O banks	–0.34/1.39	–0.34/1.53	–0.34/1.73	ns

Table 82: **Sample Window**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
T_{SAMP}	Sampling error at receiver pins(1)	0.51	0.56	0.61	ns
T_{SAMP_BUFIO}	Sampling error at receiver pins using BUFIO(2)	0.30	0.35	0.40	ns

Notes:

1. This parameter indicates the total sampling error of the PL DDR input registers, measured across voltage, temperature, and process. The characterization methodology uses the MMCM to capture the DDR input registers' edges of operation. These measurements include:
   - CLK0 MMCM jitter
   - MMCM accuracy (phase offset)
   - MMCM phase shift resolution

   These measurements do not include package or clock tree skew.
2. This parameter indicates the total sampling error of the PL DDR input registers, measured across voltage, temperature, and process. The characterization methodology uses the BUFIO clock network and IDELAY to capture the DDR input registers' edges of operation. These measurements do not include package or clock tree skew.

Additional Package Parameter Guidelines

The parameters in this section provide the necessary values for calculating timing budgets for PL clock transmitter and receiver data-valid windows.

Table 83: **Package Skew**

Symbol	Description	Device	Package	Value	Units
$T_{PKGSKEW}$	Package skew(1)	XC7Z030	FBG484	113	ps
			FBG676	113	ps
			FFG676	136	ps
		XC7Z045	FBG676	159	ps
			FFG676	158	ps
			FFG900	191	ps
		XC7Z100	FFG900		ps
			FFG1156		ps

Notes:

1. These values represent the worst-case skew between any two SelectIO resources in the package: shortest delay to longest delay from die pad to ball.
2. Package delay information is available for these device/package combinations. This information can be used to deskew the package.

GTX Transceiver Specifications

GTX Transceiver DC Input and Output Levels

Table 84 summarizes the DC specifications of the GTX transceivers in Zynq-7000 devices. Consult UG476: *7 Series FPGAs GTX/GTH Transceivers User Guide* for further details.

Table 84: **GTX Transceiver DC Specifications**

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
DV_{PPOUT}	Differential peak-to-peak output voltage(1)	Transmitter output swing is set to maximum setting	–	–	1000	mV
$V_{CMOUTDC}$	DC common mode output voltage.	Equation based	$V_{MGTAVTT} - DV_{PPOUT}/4$			mV
R_{OUT}	Differential output resistance		–	100	–	Ω
T_{OSKEW}	Transmitter output pair (TXP and TXN) intra-pair skew		–	2	12	ps
DV_{PPIN}	Differential peak-to-peak input voltage (external AC coupled)	>10.3125 Gb/s	150	–	1250	mV
		6.6 Gb/s to 10.3125 Gb/s	150	–	1250	mV
		≤ 6.6 Gb/s	150	–	2000	mV
V_{IN}	Absolute input voltage	DC coupled $V_{MGTAVTT}$ = 1.2V	–200	–	$V_{MGTAVTT}$	mV
V_{CMIN}	Common mode input voltage	DC coupled $V_{MGTAVTT}$ = 1.2V	–	2/3 $V_{MGTAVTT}$	–	mV
R_{IN}	Differential input resistance		–	100	–	Ω
C_{EXT}	Recommended external AC coupling capacitor(2)		–	100	–	nF

Notes:

1. The output swing and preemphasis levels are programmable using the attributes discussed in UG476: *7 Series FPGAs GTX/GTH Transceivers User Guide* and can result in values lower than reported in this table.
2. Other values can be used as appropriate to conform to specific protocols and standards.

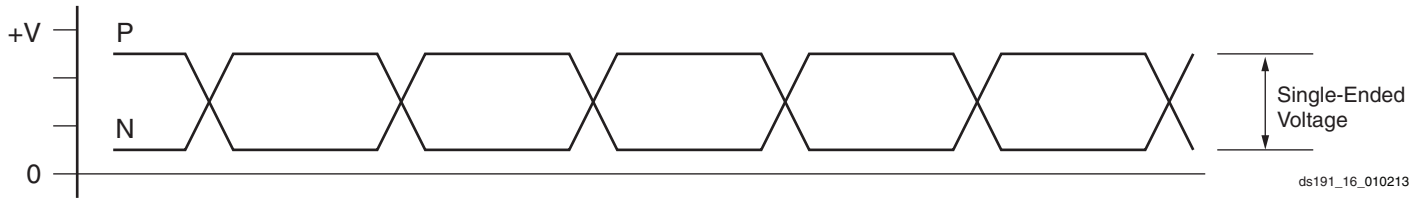

Figure 17: **Single-Ended Peak-to-Peak Voltage**

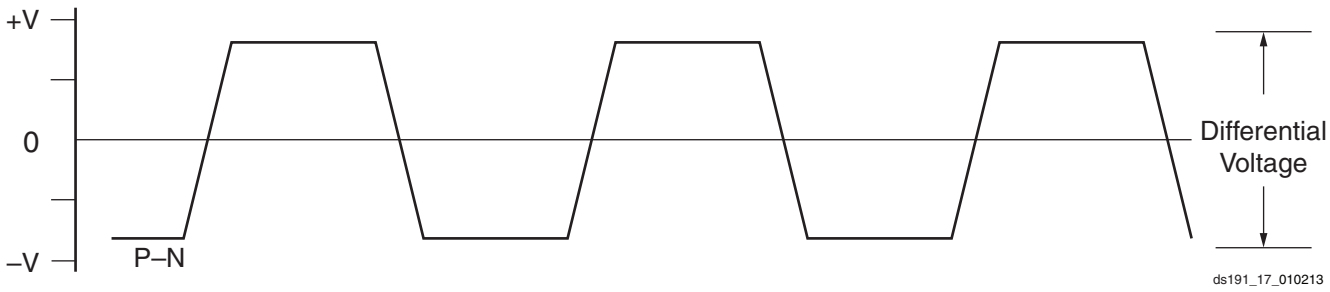

Figure 18: **Differential Peak-to-Peak Voltage**

Table 85 summarizes the DC specifications of the clock input of the GTX transceiver. Consult UG476: *7 Series FPGAs GTX/GTH Transceivers User Guide* for further details.

Table 92: **GTX Transceiver Receiver Switching Characteristics**

Symbol	Description		Min	Typ	Max	Units
F_{GTXRX}	Serial data rate	RX oversampler not enabled	0.500	–	F_{GTXMAX}	Gb/s
$T_{RXELECIDLE}$	Time for RXELECIDLE to respond to loss or restoration of data		–	10	–	ns
$RX_{OOBVDPP}$	OOB detect threshold peak-to-peak		60	–	150	mV
RX_{SST}	Receiver spread-spectrum tracking(1)	Modulated @ 33 KHz	–5000	–	0	ppm
RX_{RL}	Run length (CID)		–	–	512	UI
RX_{PPMTOL}	Data/REFCLK PPM offset tolerance	Bit rates ≤ 6.6 Gb/s	–1250	–	1250	ppm
		Bit rates > 6.6 Gb/s and ≤ 8.0 Gb/s	–700	–	700	ppm
		Bit rates > 8.0 Gb/s	–200	–	200	ppm
SJ Jitter Tolerance(2)						
$JT\_SJ_{12.5}$	Sinusoidal jitter (QPLL)(3)	12.5 Gb/s	0.3	–	–	UI
$JT\_SJ_{11.18}$	Sinusoidal jitter (QPLL)(3)	11.18 Gb/s	0.3	–	–	UI
$JT\_SJ_{10.32}$	Sinusoidal jitter (QPLL)(3)	10.32 Gb/s	0.3	–	–	UI
$JT\_SJ_{9.95}$	Sinusoidal jitter (QPLL)(3)	9.95 Gb/s	0.3	–	–	UI
$JT\_SJ_{9.8}$	Sinusoidal jitter (QPLL)(3)	9.8 Gb/s	0.3	–	–	UI
$JT\_SJ_{8.0}$	Sinusoidal jitter (QPLL)(3)	8.0 Gb/s	0.44	–	–	UI
$JT\_SJ_{6.6\_QPLL}$	Sinusoidal jitter (QPLL)(3)	6.6 Gb/s	0.48	–	–	UI
$JT\_SJ_{6.6\_CPLL}$	Sinusoidal jitter (CPLL)(3)	6.6 Gb/s	0.44	–	–	UI
$JT\_SJ_{5.0}$	Sinusoidal jitter (CPLL)(3)	5.0 Gb/s	0.44	–	–	UI
$JT\_SJ_{4.25}$	Sinusoidal jitter (CPLL)(3)	4.25 Gb/s	0.44	–	–	UI
$JT\_SJ_{3.75}$	Sinusoidal jitter (CPLL)(3)	3.75 Gb/s	0.44	–	–	UI
$JT\_SJ_{3.2}$	Sinusoidal jitter (CPLL)(3)	3.2 Gb/s(4)	0.45	–	–	UI
$JT\_SJ_{3.2L}$	Sinusoidal jitter (CPLL)(3)	3.2 Gb/s(5)	0.45	–	–	UI
$JT\_SJ_{2.5}$	Sinusoidal jitter (CPLL)(3)	2.5 Gb/s(6)	0.5	–	–	UI
$JT\_SJ_{1.25}$	Sinusoidal jitter (CPLL)(3)	1.25 Gb/s(7)	0.5	–	–	UI
JT_SJ_{500}	Sinusoidal jitter (CPLL)(3)	500 Mb/s	0.4	–	–	UI
SJ Jitter Tolerance with Stressed Eye(2)						
$JT\_TJSE_{3.2}$	Total jitter with stressed eye(8)	3.2 Gb/s	0.70	–	–	UI
		6.6 Gb/s	0.70	–	–	UI
$JT\_SJSE_{3.2}$	Sinusoidal jitter with stressed eye(8)	3.2 Gb/s	0.1	–	–	UI
		6.6 Gb/s	0.1	–	–	UI

Notes:

1. Using RXOUT_DIV = 1, 2, and 4.
2. All jitter values are based on a bit error ratio of $1e^{-12}$.
3. The frequency of the injected sinusoidal jitter is 10 MHz.
4. CPLL frequency at 3.2 GHz and RXOUT_DIV = 2.
5. CPLL frequency at 1.6 GHz and RXOUT_DIV = 1.
6. CPLL frequency at 2.5 GHz and RXOUT_DIV = 2.
7. CPLL frequency at 2.5 GHz and RXOUT_DIV = 4.
8. Composite jitter with RX and LPM or DFE mode.

Table 100: **XADC Specifications *(Cont'd)***

Parameter	Symbol	Comments/Conditions	Min	Typ	Max	Units
DCLK Duty Cycle			40	–	60	%
XADC Reference(5)						
External Reference	V_{REFP}	Externally supplied reference voltage	1.20	1.25	1.30	V
On-Chip Reference		Ground V_{REFP} pin to AGND, T_j = –40°C to 100°C	1.2375	1.25	1.2625	V

Notes:

1. Offset and gain errors are removed by enabling the XADC automatic gain calibration feature. The values are specified for when this feature is enabled.
2. Only specified for new BitGen option XADCEnhancedLinearity = ON.
3. See the ADC chapter in UG480: *7 Series FPGAs XADC User Guide* for a detailed description.
4. See the Timing chapter in UG480: *7 Series FPGAs XADC User Guide* for a detailed description.
5. Any variation in the reference voltage from the nominal V_{REFP} = 1.25V and V_{REFN} = 0V will result in a deviation from the ideal transfer function. This also impacts the accuracy of the internal sensor measurements (i.e., temperature and power supply). However, for external ratiometric type applications allowing reference to vary by ±4% is permitted. On-chip reference variation is ±1%.

Configuration Switching Characteristics

Table 101: **Configuration Switching Characteristics**

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
Power-up Timing Characteristics					
T_{POR}	Power-on reset	50.00	50.00	50.00	ms, Max
Boundary-Scan Port Timing Specifications					
T_{TAPTCK}/T_{TCKTAP}	TMS and TDI setup/hold	3.00/2.00	3.0/2.0	3.0/2.0	ns, Min
T_{TCKTDO}	TCK falling edge to TDO output	7.00	7.00	7.00	ns, Max
F_{TCK}	TCK frequency	66.00	66.00	66.00	MHz, Max
Internal Configuration Access Port					
F_{ICAPCK}	Internal configuration access port (ICAPE2)	100.00	100.00	100.00	MHz, Max

eFUSE Programming Conditions

Table 102 lists the programming conditions specifically for eFUSE. For more information, see UG470: *7 Series FPGA Configuration User Guide*.

Table 102: **eFUSE Programming Conditions**(1)

Symbol	Description	Min	Typ	Max	Units
I_{FS}	V_{CCAUX} supply current	–	–	115	mA
t_j	Temperature range	15	–	125	°C

Notes:

1. The Zynq-7000 device must not be configured during eFUSE programming.